

Contents

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Fundamental Problems of Epitaxy of Semiconductor Nanoheterostructures

- Formation of Ordered Groups of Quantum Dots During Ge/Si Heteroepitaxy
*V. A. Zinov'ev, A. V. Dvurechenskii, P. A. Kuchinskaya, V. A. Armbrister,
and A. V. Mudryi* 423
- Growth of AlGaN/GaN Heterostructures with a Two-Dimensional Electron Gas
on AlN/Al₂O₃ Substrates
*T. V. Malin, V. G. Mansurov, A. M. Gilinskii, D. Yu. Protasov, A. S. Kozhukhov,
A. P. Vasilenko, and K. S. Zhuravlev* 429
- Formation and Structural Features of Silicon Quantum Dots in Germanium
*N. P. Stepina, A. F. Zinov'eva, A. S. Deryabin, V. A. Zinov'ev, V. A. Volodin,
A. A. Shklyayev, A. V. Dvurechenskii, and S. V. Gaponenko* 434
-

Numerical Modeling of Nanoheterostructure Growth, Strain Fields, and Energy Spectrum

- Two-Dimensional Strain Distribution in Elastically Anisotropic Heterostructures
A. V. Nenashev, A. A. Koshkarev, and A. V. Dvurechenskii 440
- Applicability of the Six-Band kp-Model Equations to Semiconductor Heterostructures
*V. P. Zhukov, M. P. Fedoruk, A. F. Zinov'eva, A. V. Nenashev,
and A. V. Dvurechenskii* 450
- Three-Dimensional Model of Heteroepitaxial Growth of Germanium on Silicon
*S. A. Rudin, V. A. Zinov'ev, A. V. Nenashev, A. Yu. Polyakov, Zh. V. Smagina,
and A. V. Dvurechenskii* 461
-

Nanoheterostructures for Photoelectric Converters and Photodetector Tubes

- Ge/Si Heterostructures with Ge Quantum Dots for Mid-Infrared Photodetectors
A. I. Yakimov 467
- HgCdTe Structures for Dual-Band Photodetectors Operating in the 3–5 and 8–12 μm
Spectral Ranges
*V. S. Varavin, S. A. Dvoretckii, D. G. Ikusov, N. N. Mikhailov, V. G. Remesnik,
G. Yu. Sidorov, Yu. G. Sidorov, P. N. Sizikov, and I. N. Uzhakov* 476
- High-Performance 320 \times 256 Long-Wavelength Infrared Photodetector Arrays
Based on CdHgTe Layers Grown by Molecular Beam Epitaxy
*A. V. Predein, Yu. G. Sidorov, I. V. Sabinina, V. V. Vasil'ev, G. Yu. Sidorov,
and I. V. Marchishin* 485
- Terahertz Detectors Based on Pb_{1-x}Sn_xTe:In Films
*A. N. Akimov, D. V. Ishchenko, A. E. Klimov, I. G. Neizvestny, N. S. Pashchin,
V. N. Sherstyakova, V. N. Shumsky, and V. S. Epov* 492
-

Fundamental Problems of Photonic Devices Based on Semiconductor Nanoheterostructures

Spectroscopy of Single InAs Quantum Dots

*A. V. Gaisler, A. S. Jaroshevich, I. A. Derebezov, A. K. Kalagin, A. K. Bakarov,
A. I. Toropov, D. V. Shcheglov, V. A. Gaisler, A. V. Latyshev, and A. L. Aseev* 498

Surface-Enhanced Raman Scattering by Semiconductor Nanostructures

*A. G. Milekhin, L. L. Sveshnikova, T. A. Duda, N. A. Yeryukov,
N. V. Surovtsev, S. V. Adichtchev, E. E. Rodyakina, A. K. Gutakovskii,
A. V. Latyshev, and D. R. T. Zahn* 504

Semiconductor Nanoheterostructures for Spintronics

Microsecond Lifetime of Exciton Spin Polarization in (In,Al)As/AlAs Quantum Dots

*T. S. Shamirzaev, D. Dunker, J. Debus, D. R. Yakovlev, K. S. Zhuravlev,
and M. Bayer* 514

Fundamental Problems of Biosensorics on the Basis of Nanoheterostructures

SOI Nanowire Transistor for Detection of D-NFATc1 Molecules

*Yu. D. Ivanov, T. O. Pleshakova, A. F. Kozlov, K. A. Mal'sagova, N. V. Krokhin,
A. L. Kaisheva, I. D. Shumov, V. P. Popov, O. V. Naumova, B. I. Fomin,
D. A. Nasimov, A. L. Aseev, and A. I. Archakov* 520
